#### **BYV42E series**

#### GENERAL DESCRIPTION

Glass passivated high efficiency rugged dual rectifier diodes in a plastic envelope, featuring low forward voltage drop, ultra-fast recovery times and soft recovery characteristic. These devices can withstand reverse voltage transients and have guaranteed reverse surge and ESD capability. They are intended for use in switched mode power supplies and high frequency circuits in general where low conduction and switching losses are essential.

#### PINNING - TO220AB

# PINDESCRIPTION1anode 1 (a)2cathode (k)3anode 2 (a)tabcathode (k)

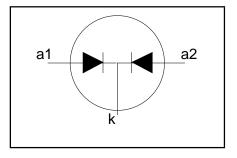
#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V <sub>RRM</sub>	BYV42E- Repetitive peak reverse voltage	<b>100</b> 100	<b>150</b> 150	<b>200</b> 200	V
V <sub>F</sub> I <sub>O(AV)</sub>	Forward voltage Output current (both diodes conducting)	0.85 30	0.85 30	0.85 30	V A
t <sub>rr</sub> I <sub>RRM</sub>	Reverse recovery time Repetitive peak reverse current per diode	28 0.2	28 0.2	28 0.2	ns A

#### **PIN CONFIGURATION**

tab

#### SYMBOL



#### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT
V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	Repetitive peak reverse voltage Crest working reverse voltage Continuous reverse voltage			<b>-100</b> 100 100 100	<b>-150</b> 150 150 150	<b>-200</b> 200 200 200	V V V
I <sub>O(AV)</sub>	Output current (both diodes conducting) <sup>2</sup>	square wave $\delta = 0.5; T_{mb} \le 108 ^{\circ}C$ sinusoidal $a = 1.57; T_{mb} \le 111 ^{\circ}C$	-		30 27		A A
I <sub>O(RMS)</sub> I <sub>FRM</sub>	RMS forward current Repetitive peak forward current per diode	t = 25 μs; δ = 0.5; T <sub>mb</sub> ≤ 108 °C	-		43 30		A A
I <sub>FSM</sub>	Non-repetitive peak forward current per diode	t = 10 ms t = 8.3 ms sinusoidal; with reapplied V <sub>RWM(max)</sub>	-		150 160		A A
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t = 10  ms	-		112		A <sup>2</sup> s
I <sub>RRM</sub>	Repetitive peak reverse current per diode		-		0.2		A
I <sub>RSM</sub>	Non-repetitive peak reverse current per diode	t <sub>p</sub> = 100 μs	-		0.2		A
$\begin{array}{c} T_{stg} \\ T_{j} \end{array}$	Storage temperature Operating junction temperature		-40 -		150 150		°C °C

 $1 T_{mb} \le 144^{\circ}C$  for thermal stability.

2 Neglecting switching and reverse current losses.

For output currents in excess of 20 A, connection should be made to the exposed metal mounting base.

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#### ESD LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>c</sub>	Electrostatic discharge capacitor voltage	Human body model; C = 250 pF; R = 1.5 k $\Omega$	-	8	kV

#### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-mb</sub> R <sub>th j-a</sub>	mounting base	per diode both diodes conducting in free air	-	- - 60	2.4 1.4 -	K/W K/W K/W

#### STATIC CHARACTERISTICS

 $T_i = 25$  °C unless otherwise stated

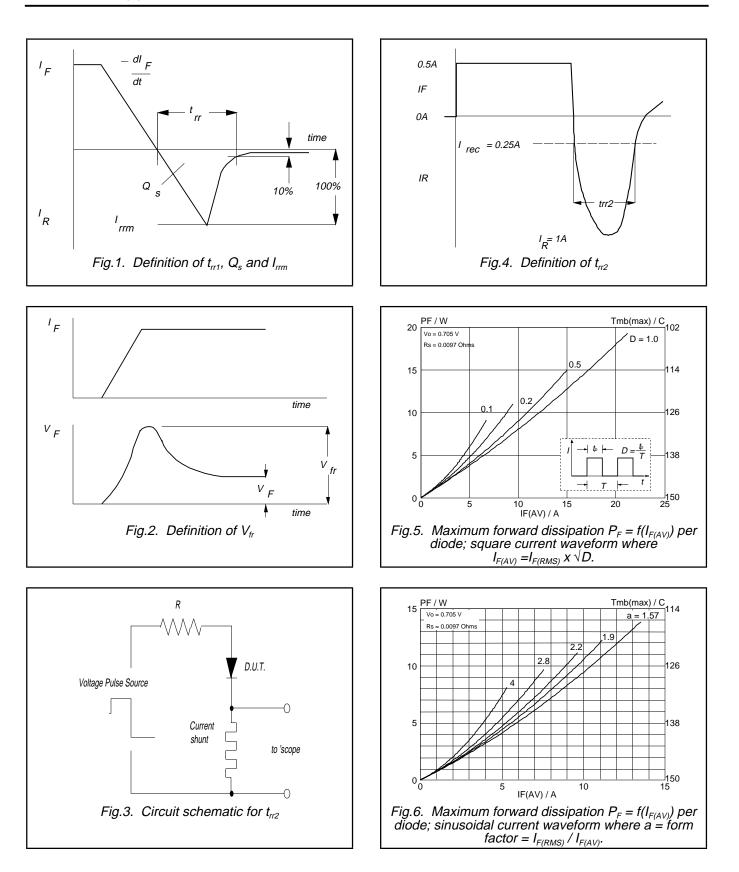
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	Forward voltage (per diode)	I <sub>F</sub> = 15 A; T <sub>j</sub> = 150°C I <sub>F</sub> = 15 A	-	0.78	0.85	V
		I <sub>F</sub> = 15 A	-	0.95	1.05	V
		$I_{\rm F} = 30  {\rm A}$	-	1.00	1.20	V
I <sub>R</sub>	Reverse current (per diode)	$\dot{V}_{R} = V_{RWM}; T_{i} = 100 ^{\circ}\text{C}$	-	0.5	1	mA
		$V_{R} = V_{RWM}$	-	10	100	μΑ

#### **DYNAMIC CHARACTERISTICS**

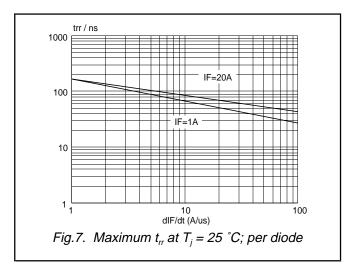
 $T_i = 25$  °C unless otherwise stated

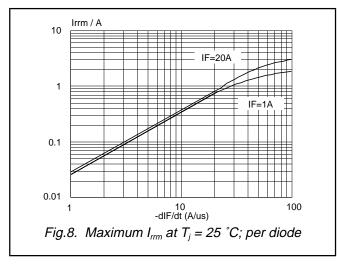
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Q <sub>s</sub>	Reverse recovery charge (per diode)	$I_{\text{F}} = 2 \text{ A};  V_{\text{R}} \geq 30  \text{V};  \text{-d}I_{\text{F}}\text{/d}t = 20  \text{A}\text{/}\mu\text{s}$	-	6	15	nC
t <sub>rr1</sub>	Reverse recovery time (per diode)	I <sub>F</sub> = 1 A; V <sub>R</sub> ≥ 30 V; -dI <sub>F</sub> /dt = 100 A/μs	-	20	28	ns
t <sub>rr2</sub>	Reverse recovery time (per diode)	$I_{\rm F} = 0.5 \text{ A to } I_{\rm R} = 1 \text{ A}; I_{\rm rec} = 0.25 \text{ A}$	-	13	22	ns
V <sub>fr</sub>	Forward recovery voltage (per diode)	$I_{F} = 1 \text{ A}; \text{ d}I_{F}/\text{d}t = 10 \text{ A}/\mu\text{s}$	-	1	-	V

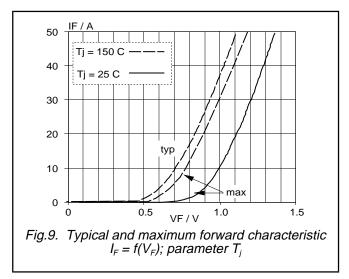
#### **BYV42E** series

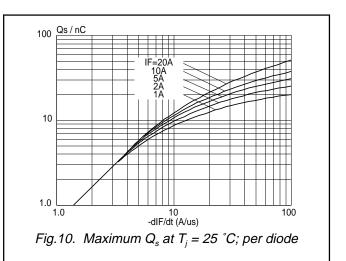


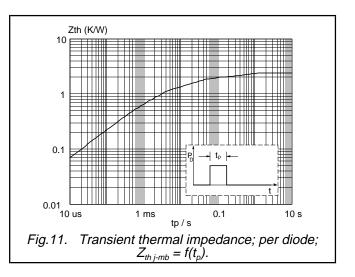
### BYV42E series







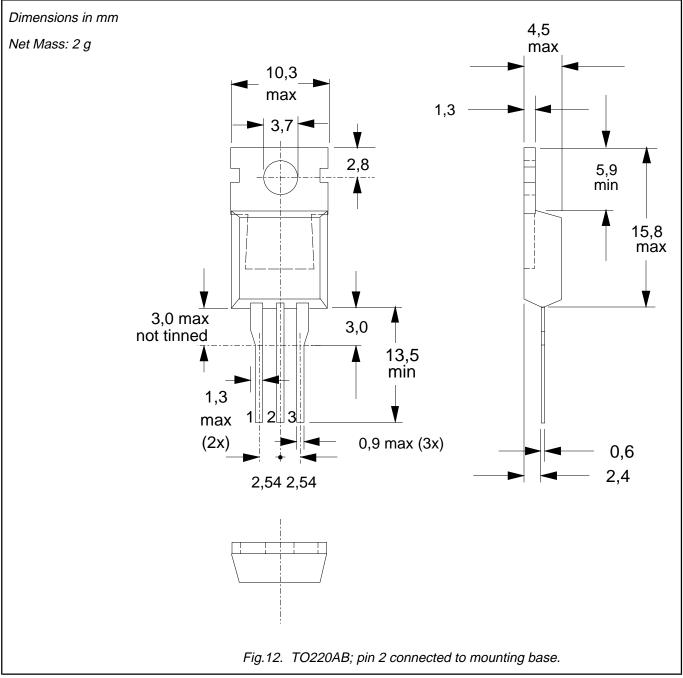




#### **Product specification**

#### **BYV42E** series

#### **MECHANICAL DATA**



#### Notes

Accessories supplied on request: refer to mounting instructions for TO220 envelopes.
Epoxy meets UL94 V0 at 1/8".

#### **BYV42E** series

#### DEFINITIONS

Data sheet status				
Objective specification	ve specification This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	Product specification This data sheet contains final product specifications.			
Limiting values				
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.				

#### Application information

Where application information is given, it is advisory and does not form part of the specification.

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